



Micro Commercial Components



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MCP140N10Y

N-Channel Enhancement Mode Field Effect Transistor

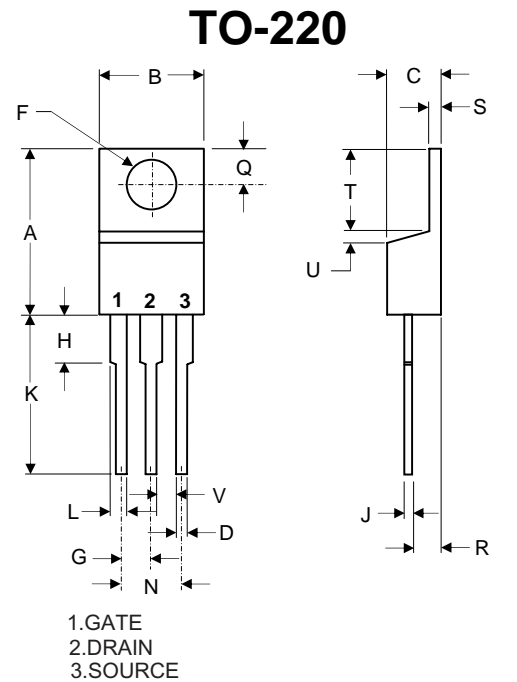
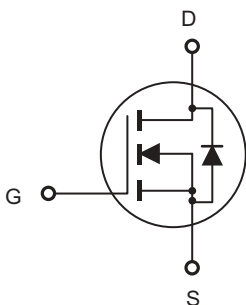
Features

- Trench Power MV MOSFET technology
- Low $R_{DS(ON)}$
- Halogen free available upon request by adding suffix "-HF"
- Low Gate Charge
- Optimized for fast-switching applications
- Epoxy meets UL 94 V-0 flammability rating
- Moisture Sensitivity Level 1

Maximum Ratings @ 25°C Unless Otherwise Specified

Symbol	Parameter	Rating	Unit
V_{DS}	Drain-source Voltage	100	V
I_{DM}	Pulsed Drain Current (Note 3)	500	A
I_D	Continuous Drain Current (Note 7)	$T_C = 25^\circ\text{C}$	140
		$T_C = 100^\circ\text{C}$	115
V_{GS}	Gate-source Voltage	± 20	V
P_{DSM}	Power Dissipation (Note 1)	$T_C = 25^\circ\text{C}$	220
		$T_C = 100^\circ\text{C}$	110
E_{AS}	Single pulse avalanche energy (Note 3)	800	mj
T_J	Operating Junction Temperature	-55 to +175	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 to +175	$^\circ\text{C}$

Internal Block Diagram



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	.560	.625	14.22	15.88	
B	.380	.420	9.65	10.67	
C	.140	.190	3.56	4.82	
D	.020	.045	0.51	1.14	
F	.134	.161	3.40	4.09	∅
G	.190	.110	2.29	2.79	
H	---	.250	---	6.35	
J	.012	.025	0.30	0.64	
K	.500	.580	12.70	14.73	
L	.045	.060	1.14	1.52	
N	.190	.210	4.83	5.33	
Q	.100	.135	2.54	3.43	
R	.080	.115	2.04	2.92	
S	.045	.055	1.14	1.39	
T	.230	.270	5.84	6.86	
U	----	.050	----	1.27	
V	.045	----	1.15	----	

Electrical characteristics ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
STATIC PARAMETERS						
BV_{DSS}	Drain-Source Breakdown Voltage	$I_D=250\mu\text{A}$, $V_{GS}=0\text{V}$	100			V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=100\text{V}$, $V_{GS}=0\text{V}$			1	μA
			$T_J=55^\circ\text{C}$		5	
I_{GSS}	Gate-Body leakage current	$V_{DS}=0\text{V}$, $V_{GS}=\pm 20\text{V}$			± 100	nA
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$, $I_D=250\mu\text{A}$	2	3	4	V
$R_{DS(on)}$	Static Drain-Source On-Resistance	$V_{GS}=10\text{V}$, $I_D=50\text{A}$		3.3	3.9	m Ω
			$T_J=125^\circ\text{C}$	5.3	6.2	
g_{FS}	Diode Forward Voltage	$V_{DS}=5\text{V}$, $I_D=50\text{A}$	80			S
V_{SD}	Diode Forward Voltage	$I_S=50\text{A}$, $V_{GS}=0\text{V}$		0.85	0.99	V
I_S	Maximum Body-Diode Continuous Current (Note 7)				140	A
DYNAMIC PARAMETERS						
C_{iss}	Input Capacitance	$V_{GS}=0\text{V}$, $V_{DS}=50\text{V}$, $f=1\text{MHz}$		6920		pF
C_{oss}	Output Capacitance			1026		pF
C_{rss}	Reverse Transfer Capacitance			34		pF
R_g	Gate resistance	$V_{GS}=0\text{V}$, $V_{DS}=0\text{V}$, $f=1\text{MHz}$		2.6		Ω
SWITCHING PARAMETERS						
Q_g	Total Gate Charge	$V_{GS}=10\text{V}$, $V_{DS}=50\text{V}$, $I_D=50\text{A}$		117		nC
Q_{gs}	Gate Source Charge			40		nC
Q_{gd}	Gate Drain Charge			37		nC
$t_{D(on)}$	Turn-on Delay Time	$V_{GS}=10\text{V}$, $V_{DS}=50\text{V}$, $R_L=2.5\Omega$, $R_{GEN}=3\Omega$		48		ns
t_r	Turn-on Rise Time			56		ns
$t_{D(off)}$	Turn-off Delay Time			75		ns
t_f	Turn-off Fall Time			33		ns
t_{rr}	Body Diode Reverse Recovery Time	$I_F=20\text{A}$, $di/dt=500\text{A}/\mu\text{s}$		60		ns
Q_{rr}	Body Diode Reverse Recovery charge	$I_F=20\text{A}$, $di/dt=500\text{A}/\mu\text{s}$		560		nC

1. The value of $R_{\theta JA}$ is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with $T_a=25^\circ\text{C}$. The Power dissipation P_{DSM} is based on $R_{\theta JA} \leq 10\text{s}$ and the maximum allowed junction temperature of 150°C . The value in any given application depends on the user's specific board design.

2. The power dissipation P_D is based on $T_{J(MAX)}=175^\circ\text{C}$, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.

3. Single pulse width limited by junction temperature $T_{J(MAX)}=175^\circ\text{C}$.

4. The $R_{\theta JA}$ is the sum of the thermal impedance from junction to case $R_{\theta JC}$ and case to ambient.

5. The static characteristics in Figures 1 to 6 are obtained using $<300\mu\text{s}$ pulses, duty cycle 0.5% max.

6. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of $T_{J(MAX)}=175^\circ\text{C}$. The SOA curve provides a single pulse rating.

7. The maximum current rating is package limited.

Fig 1: Output Characteristics

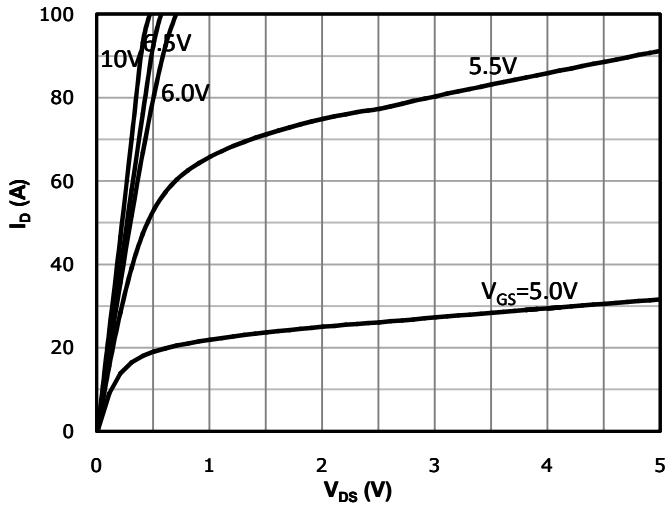


Fig 2: Transfer Characteristics

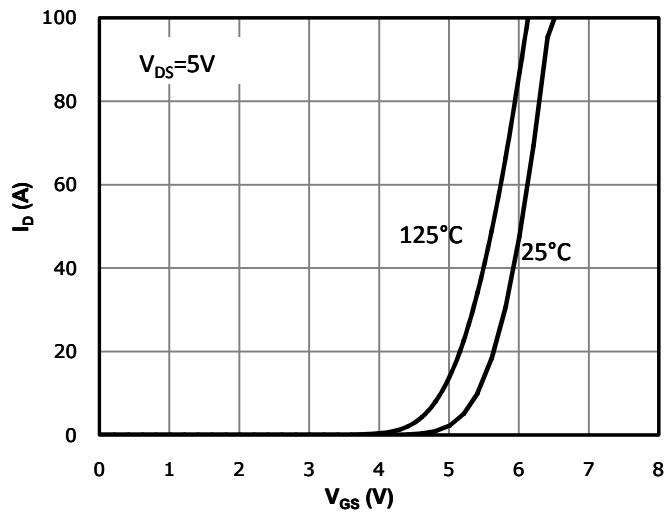


Fig 3: $R_{DS(on)}$ vs Drain Current and Gate Voltage

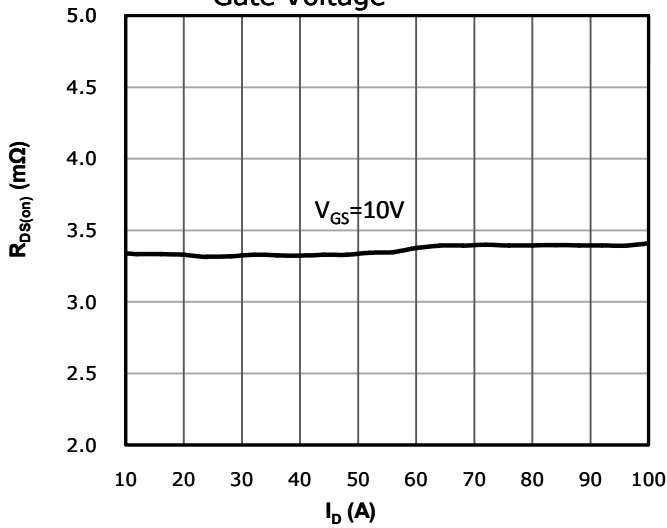


Fig 4: $R_{DS(on)}$ vs Gate Voltage

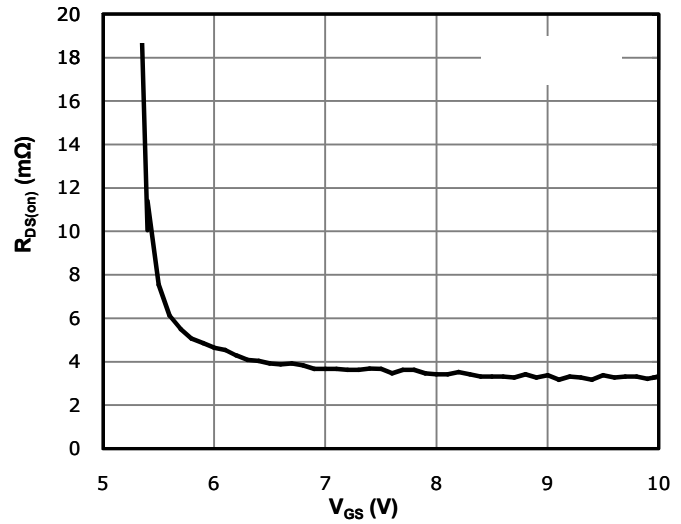


Fig 5: $R_{DS(on)}$ vs. Temperature

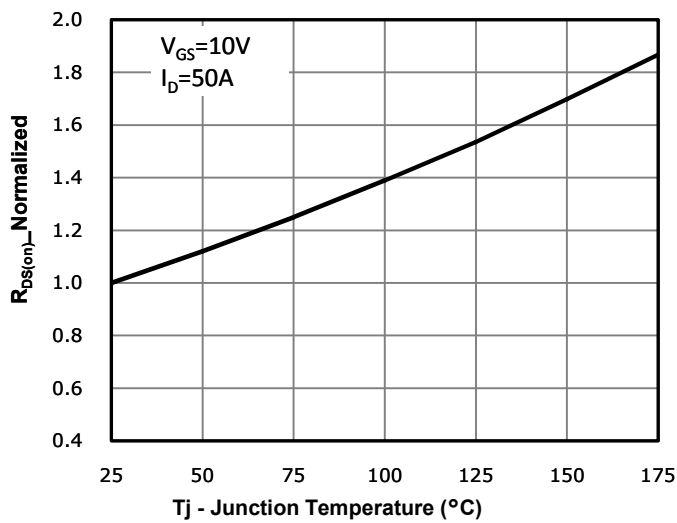


Fig 6: Capacitance Characteristics

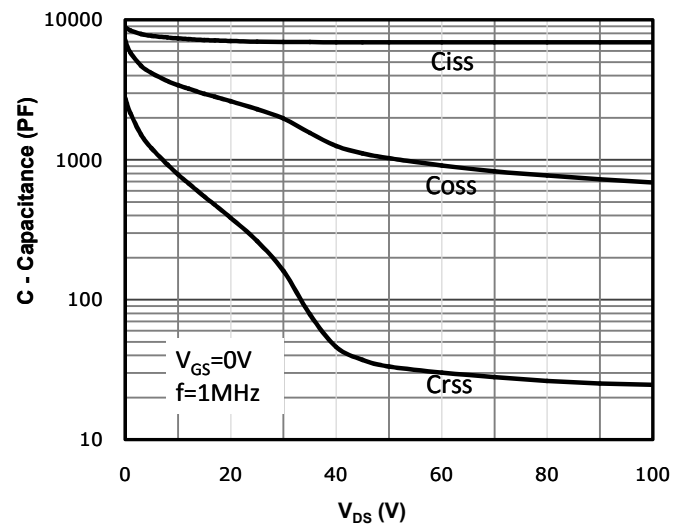


Fig 7: Gate Charge Characteristics

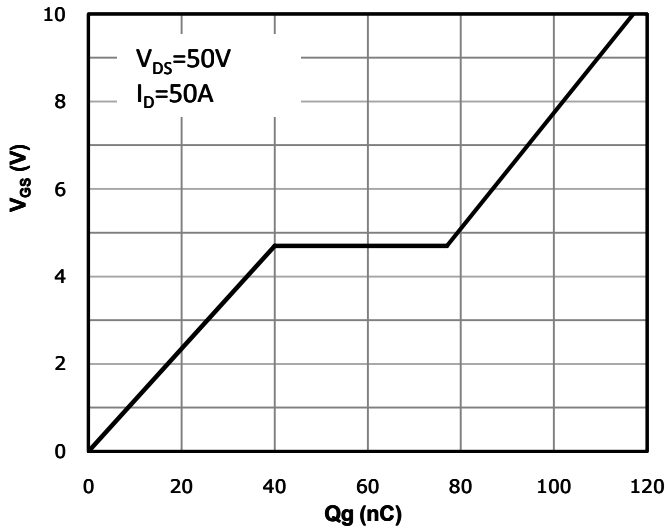


Fig 8: Body-diode Forward Characteristics

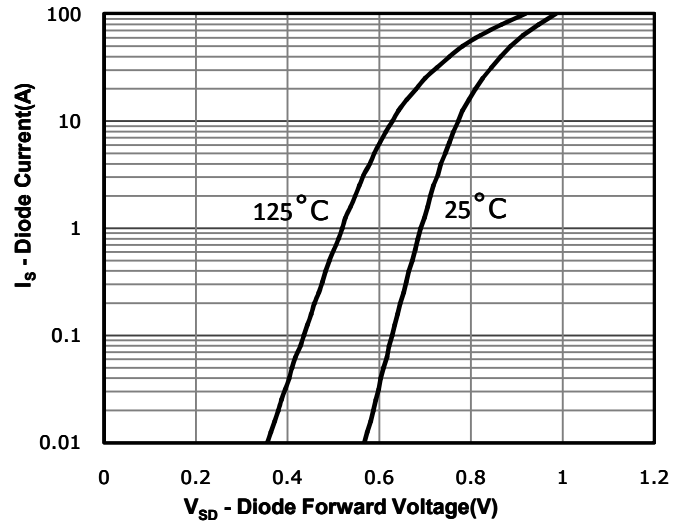


Fig 9: Power Dissipation

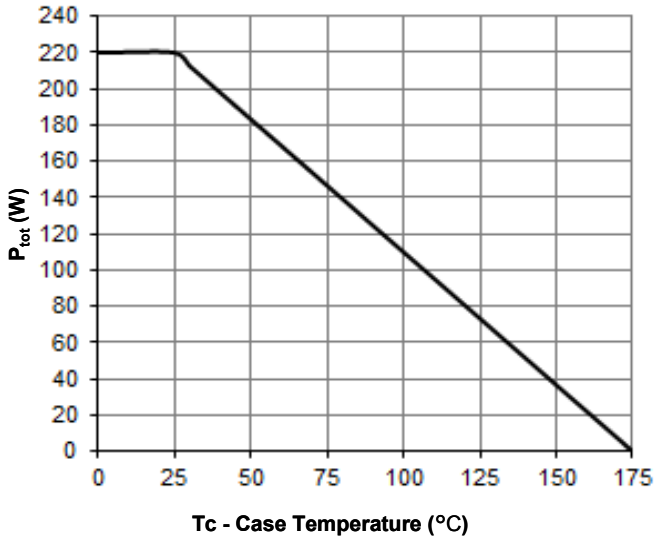


Fig 10: Drain Current Derating

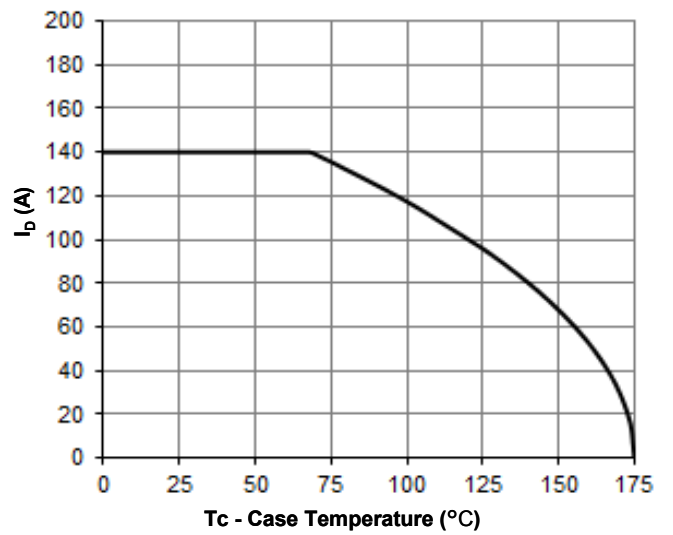
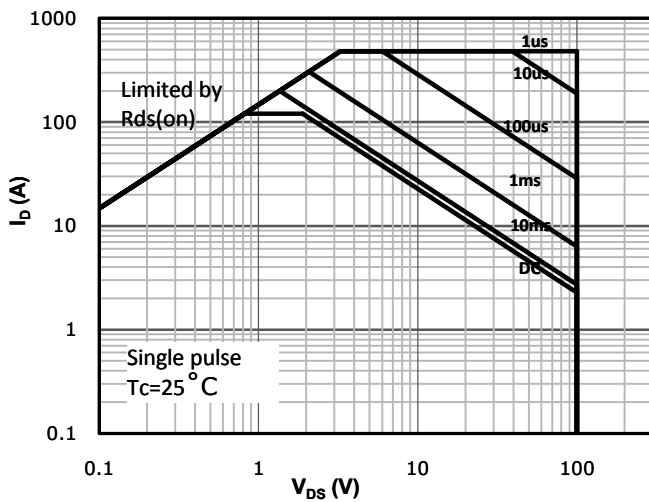


Fig 11: Safe Operating Area





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Ordering Information :

Device	Packing
Part Number-BP	Bulk; 1Kpcs/Box

Note : Adding "-HF" suffix for halogen free, eg. Part Number-BP-HF

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